

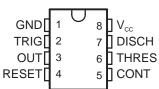
PRECISION TIMERS

Check for Samples: NA555, NE555, SA555, SE555

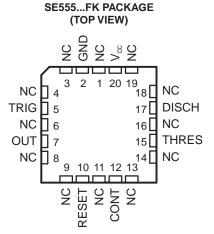
FEATURES

- Timing From Microseconds to Hours
- Astable or Monostable Operation

NA555...D OR P PACKAGE NE555...D, P, PS, OR PW PACKAGE SA555...D OR P PACKAGE SE555...D, JG, OR P PACKAGE (TOP VIEW)



- Adjustable Duty Cycle
- TTL-Compatible Output Can Sink or Source up to 200 mA



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

These devices are precision timing circuits capable of producing accurate time delays or oscillation. In the time-delay or monostable mode of operation, the timed interval is controlled by a single external resistor and capacitor network. In the astable mode of operation, the frequency and duty cycle can be controlled independently with two external resistors and a single external capacitor.

The threshold and trigger levels normally are two-thirds and one-third, respectively, of V_{CC} . These levels can be altered by use of the control-voltage terminal. When the trigger input falls below the trigger level, the flip-flop is set, and the output goes high. If the trigger input is above the trigger level and the threshold input is above the threshold level, the flip-flop is reset and the output is low. The reset (RESET) input can override all other inputs and can be used to initiate a new timing cycle. When RESET goes low, the flip-flop is reset, and the output goes low. When the output is low, a low-impedance path is provided between discharge (DISCH) and ground.

The output circuit is capable of sinking or sourcing current up to 200 mA. Operation is specified for supplies of 5 V to 15 V. With a 5-V supply, output levels are compatible with TTL inputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION(1)

T _A	V _{THRES} MAX V _{CC} = 15 V	PAC	KAGE ⁽²⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
		PDIP – P	Tube of 50	NE555P	NE555P	
		SOIC - D	Tube of 75	NE555D	NEEE	
0°C to 70°C	11.2 V	201C – D	Reel of 2500	NE555DR	NE555	
0.010.40.0		SOP – PS	Reel of 2000	NE555PSR	N555	
		TCCOD DW	Tube of 150	NE555PW	NEEE	
		TSSOP – PW	Reel of 2000	NE555PWR	N555	
		PDIP – P	Tube of 50	SA555P	SA555P	
–40°C to 85°C	11.2 V	2010	Tube of 75	SA555D	CAFFE	
		SOIC – D	Reel of 2000	SA555DR	SA555	
		PDIP – P	Tube of 50	NA555P	NA555P	
–40°C to 105°C	11.2 V	COIC D	Tube of 75	NA555D	NACCE	
		SOIC – D	Reel of 2000	NA555DR	NA555	
		PDIP – P	Tube of 50	SE555P	SE555P	
		2010 D	Tube of 75	SE555D	CLEED	
–55°C to 125°C	10.6	SOIC – D	Reel of 2500	SE555DR	SE555D	
		CDIP – JG	Tube of 50	SE555JG	SE555JG	
1		LCCC – FK	Tube of 55	SE555FK	SE555FK	

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

Table 1. FUNCTION TABLE

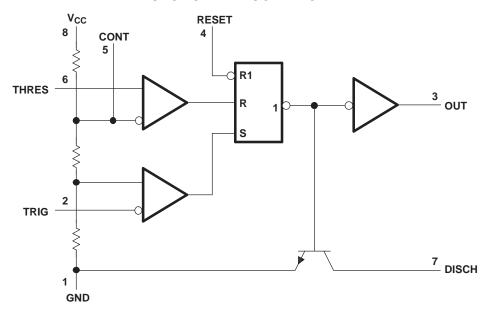
RESET	TRIGGER VOLTAGE ⁽¹⁾	THRESHOLD VOLTAGE ⁽¹⁾	ОИТРИТ	DISCHARGE SWITCH
Low	Irrelevant	Irrelevant	Low	On
High	<1/3 V _{CC}	Irrelevant	High	Off
High	>1/3 V _{CC}	>2/3 V _{CC}	Low	On
High	>1/3 V _{CC}	<2/3 V _{CC}	As previou	usly established

(1) Voltage levels shown are nominal.

⁽²⁾ Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



FUNCTIONAL BLOCK DIAGRAM



- A. Pin numbers shown are for the D, JG, P, PS, and PW packages.
- B. RESET can override TRIG, which can override THRES.



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage (2)			18	V
VI	Input voltage	CONT, RESET, THRES, TRIG		V _{CC}	V
Io	Output current			±225	mA
		D package		97	
0	Dealers thereal impacts (3) (4)	P package		85	90.444
θ_{JA}	Package thermal impedance (3) (4)	PS package		95	°C/W
		PW package		149	
0	Deal (5) (6)	FK package		5.61	90.444
θ JC	Package thermal impedance ⁽⁵⁾ (6)	JG package		14.5	°C/W
TJ	Operating virtual junction temperature			150	°C
	Case temperature for 60 s	FK package		260	°C
	Lead temperature 1, 6 mm (1/16 in) from case for 60 s	JG package		300	°C
T _{stg}	Storage temperature range		-65	150	°C

- Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltage values are with respect to GND.
- Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.
- Maximum power dissipation is a function of T_J(max), θ_{JC}, and T_C. The maximum allowable power dissipation at any allowable case temperature is $P_D = (T_J(max) - T_C)/\theta_{JC}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- The package thermal impedance is calculated in accordance with MIL-STD-883.

Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V	Cupply valtage	NA555, NE555, SA555	4.5	16	V
V _{CC}	Supply voltage	SE555	4.5	18	V
V_{I}	Input voltage	CONT, RESET, THRES, and TRIG		V_{CC}	٧
Io	Output current	·		±200	mA
		NA555	-40	105	
_	Operating free air temperature	NE555	0	70	°C
T _A	Operating free-air temperature	SA555	-40	85	
		SE555	- 55	125	



Electrical Characteristics

 $V_{CC} = 5 \text{ V}$ to 15 V, $T_A = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONE			SE555			NA555 NE555 SA555		UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
TUDEO 1: 1	V _{CC} = 15 V		9.4	10	10.6	8.8	10	11.2	
THRES voltage level	V _{CC} = 5 V		2.7	3.3	4	2.4	3.3	4.2	V
THRES current ⁽¹⁾				30	250		30	250	nA
	V 45.V		4.8	5	5.2	4.5	5	5.6	
TDIO colleges level	V _{CC} = 15 V	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$	3		6				
TRIG voltage level	.,		1.45	1.67	1.9	1.1	1.67	2.2	V
	$V_{CC} = 5 V$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			1.9				
TRIG current	TRIG at 0 V			0.5	0.9		0.5	2	μΑ
			0.3	0.7	1	0.3	0.7	1	
RESET voltage level	$T_A = -55$ °C to 125°C				1.1				V
DEGET	RESET at V _{CC}			0.1	0.4		0.1	0.4	
RESET current	RESET at 0 V			-0.4	-1		-0.4	-1.5	mA
DISCH switch off-state current				20	100		20	100	nA
	V 45.V		9.6	10	10.4	9	10	11	
CONT voltage	V _{CC} = 15 V	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$	9.6		10.4				
(open circuit)	.,,		2.9	3.3	3.8	2.6	3.3	4	V
	$V_{CC} = 5 V$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$	2.9		3.8				
	V 45.V L 40. A			0.1	0.15		0.1	0.25	
	$V_{CC} = 15 \text{ V}, I_{OL} = 10 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			0.2				
	V 45.V I 50 A			0.4	0.5		0.4	0.75	
	$V_{CC} = 15 \text{ V}, I_{OL} = 50 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			1				
	., .=., .			2	2.2		2	2.5	
Low-level output voltage	$V_{CC} = 15 \text{ V}, I_{OL} = 100 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			2.7				V
	V _{CC} = 15 V, I _{OL} = 200 mA			2.5			2.5		
	$V_{CC} = 5 \text{ V}, I_{OL} = 3.5 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			0.35				
				0.1	0.2		0.1	0.35	
	$V_{CC} = 5 \text{ V}, I_{OL} = 5 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$			0.8				
	V _{CC} = 5 V, I _{OL} = 8 mA	,		0.15	0.25		0.15	0.4	
			13	13.3		12.75	13.3		
	$V_{CC} = 15 \text{ V}, I_{OL} = -100 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$	12						
High-level output voltage	$V_{CC} = 15 \text{ V}, I_{OH} = -200 \text{ mA}$,		12.5			12.5		V
			3	3.3		2.75	3.3		
	$V_{CC} = 5 \text{ V}, I_{OL} = -100 \text{ mA}$	$T_A = -55$ °C to 125°C	2						
	0	V _{CC} = 15 V		10	12		10	15	
0 1 :	Output low, No load	$V_{CC} = 5 \text{ V}$		3	5		3	6	
Supply current		V _{CC} = 15 V		9	10		9	13	mA
	Output high, No load	V _{CC} = 5 V		2	4		2	5	

⁽¹⁾ This parameter influences the maximum value of the timing resistors R_A and R_B in the circuit of Figure 12. For example, when V_{CC} = 5 V, the maximum value is R_A + R_B \neq 3.4 M Ω , and for V_{CC} = 15 V, the maximum value is 10 M Ω .



Operating Characteristics

 V_{CC} = 5 V to 15 V, T_A = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾	SE555			NA555 NE555 SA555			UNIT
			MIN	TYP	MAX	MIN	TYP	TYP MAX	
Initial error of timing	Each timer, monostable (3)	T _A = 25°C		0.5	1.5 ⁽⁴⁾		1	3	0/
interval ⁽²⁾	Each timer, astable ⁽⁵⁾			1.5			2.25		%
Temperature coefficient of	Each timer, monostable (3)	$T_A = MIN \text{ to } MAX$		30	100 ⁽⁴⁾		50		ppm/
timing interval	Each timer, astable (5)			90			150		. °C
Supply-voltage sensitivity of	Each timer, monostable (3)	T _A = 25°C		0.05	0.2 ⁽⁴⁾		0.1	0.5	0/ /\/
timing interval	Each timer, astable ⁽⁵⁾			0.15			0.3		%/V
Output-pulse rise time		$C_L = 15 \text{ pF},$ $T_A = 25^{\circ}\text{C}$		100	200(4)		100	300	ns
Output-pulse fall time		$C_L = 15 \text{ pF},$ $T_A = 25^{\circ}\text{C}$		100	200(4)		100	300	ns

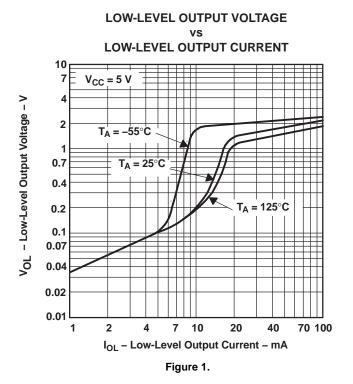
- (1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
- (2) Timing interval error is defined as the difference between the measured value and the average value of a random sample from each process run.
- (3) Values specified are for a device in a monostable circuit similar to Figure 9, with the following component values: $R_A = 2 k\Omega$ to 100 $k\Omega$, $C = 0.1 \mu F$.
- (4) On products compliant to MIL-PRF-38535, this parameter is not production tested.
- (5) Values specified are for a device in an astable circuit similar to Figure 12, with the following component values: R_A = 1 kΩ to 100 kΩ, C = 0.1 μF.

LOW-LEVEL OUTPUT VOLTAGE



TYPICAL CHARACTERISTICS

Data for temperatures below 0°C and above 70°C are applicable for SE555 circuits only.

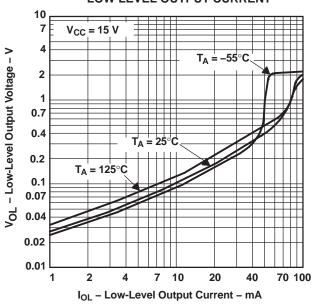


LOW-LEVEL OUTPUT CURRENT 10 V_{CC} = 10 V 7 - Low-Level Output Voltage - V 2 T_A = 25°C 0.7 0.4 0.2 0.1 0.07 ^oL 0.04 0.02 0.01 2 40 70 100 7 10 20 I_{OL} - Low-Level Output Current - mA Figure 2.

DROP BETWEEN SUPPLY VOLTAGE AND OUTPUT

HIGH-LEVEL OUTPUT CURRENT

LOW-LEVEL OUTPUT VOLTAGE LOW-LEVEL OUTPUT CURRENT 10 7 V_{CC} = 15 V



2.0 T_A = -55°C 1.8 1.6 (V_{CC} - V_{OH}) - Voltage Drop - V T_A = 25°C 1.4 1.2 T_A = 125°C 1 0.8 0.6 0.4 0.2 V_{CC} = 5 V to 15 V 0 10 20 40 70 100 IOH - High-Level Output Current - mA Figure 4.

Figure 3.



TYPICAL CHARACTERISTICS (continued)

Data for temperatures below 0°C and above 70°C are applicable for SE555 circuits only.

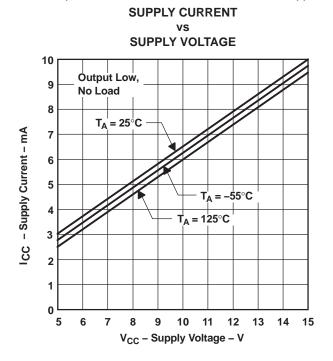


Figure 5.

NORMALIZED OUTPUT PULSE DURATION (MONOSTABLE OPERATION)

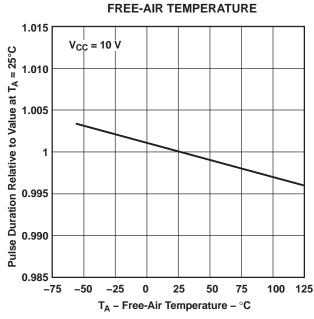
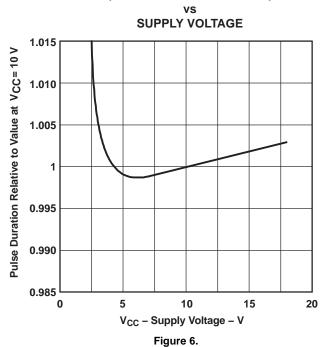


Figure 7.

NORMALIZED OUTPUT PULSE DURATION (MONOSTABLE OPERATION)



PROPAGATION DELAY TIME
vs

LOWEST VOLTAGE LEVEL OF TRIGGER PULSE

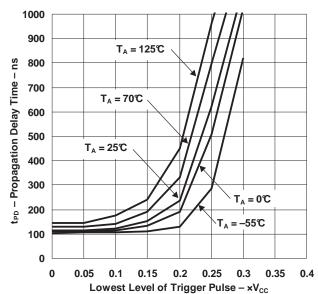


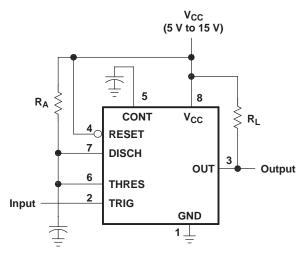
Figure 8.



APPLICATION INFORMATION

Monostable Operation

For monostable operation, any of these timers can be connected as shown in Figure 9. If the output is low, application of a negative-going pulse to the trigger (TRIG) sets the flip-flop (\overline{Q} goes low), drives the output high, and turns off Q1. Capacitor C then is charged through R_A until the voltage across the capacitor reaches the threshold voltage of the threshold (THRES) input. If TRIG has returned to a high level, the output of the threshold comparator resets the flip-flop (\overline{Q} goes high), drives the output low, and discharges C through Q1.



Pin numbers shown are for the D, JG, P, PS, and PW packages.

Figure 9. Circuit for Monostable Operation

Monostable operation is initiated when TRIG voltage falls below the trigger threshold. Once initiated, the sequence ends only if TRIG is high for at least 10 μ s before the end of the timing interval. When the trigger is grounded, the comparator storage time can be as long as 10 μ s, which limits the minimum monostable pulse width to 10 μ s. Because of the threshold level and saturation voltage of Q1, the output pulse duration is approximately $t_w = 1.1 R_A C$. Figure 11 is a plot of the time constant for various values of R_A and R_A and R_A and levels and charge rates both are directly proportional to the supply voltage, R_A and R_A independent of the supply voltage, so long as the supply voltage is constant during the time interval.

Applying a negative-going trigger pulse simultaneously to RESET and TRIG during the timing interval discharges C and reinitiates the cycle, commencing on the positive edge of the reset pulse. The output is held low as long as the reset pulse is low. To prevent false triggering, when RESET is not used, it should be connected to V_{CC} .



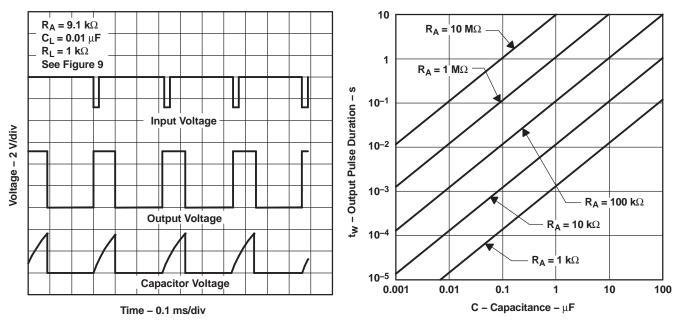


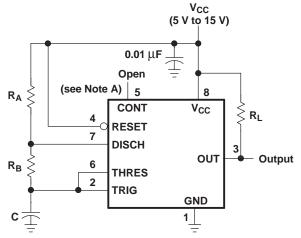
Figure 10. Typical Monostable Waveforms

Figure 11. Output Pulse Duration vs Capacitance

Astable Operation

As shown in Figure 12, adding a second resistor, R_B , to the circuit of Figure 9 and connecting the trigger input to the threshold input causes the timer to self-trigger and run as a multivibrator. The capacitor C charges through R_A and R_B and then discharges through R_B only. Therefore, the duty cycle is controlled by the values of R_A and R_B .

This astable connection results in capacitor C charging and discharging between the threshold-voltage level ($\neq 0.67 \times V_{CC}$) and the trigger-voltage level ($\neq 0.33 \times V_{CC}$). As in the monostable circuit, charge and discharge times (and, therefore, the frequency and duty cycle) are independent of the supply voltage.



Pin numbers shown are for the D, JG, P, PS, and PW packages.

NOTE A: Decoupling CONT voltage to ground with a capacitor can improve operation. This should be evaluated for individual applications.

Figure 12. Circuit for Astable Operation

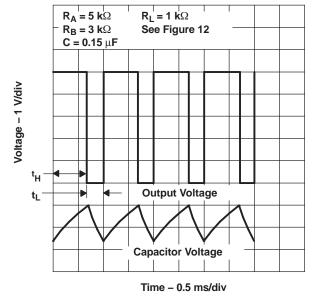


Figure 13. Typical Astable Waveforms



Figure 12 shows typical waveforms generated during astable operation. The output high-level duration t_H and low-level duration t_L can be calculated as follows:

$$t_{H} = 0.693 (R_{A} + R_{B}) C$$

 $t_{L} = 0.693 (R_{B}) C$

Other useful relationships are shown below.

$$\begin{aligned} \text{period} &= t_\text{H} + t_\text{L} = 0.693 \left(\text{R}_\text{A} + 2 \text{R}_\text{B} \right) \text{C} \\ \text{frequency} &\approx \frac{1.44}{\left(\text{R}_\text{A} + 2 \text{R}_\text{B} \right) \text{C}} \end{aligned}$$

Output driver duty cycle =
$$\frac{t_L}{t_H + t_L} = \frac{R_B}{R_A + 2R_B}$$

Output waveform duty cycle

$$= \frac{t_H}{t_H + t_L} = 1 - \frac{R_B}{R_A + 2R_B}$$
Low-to-high ratio
$$= \frac{t_L}{t_H} = \frac{R_B}{R_A + R_B}$$

Figure.

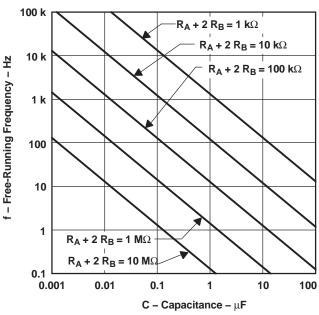
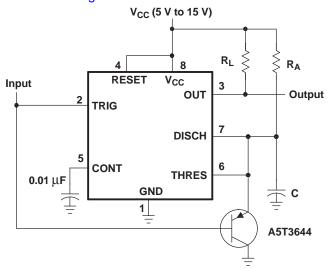


Figure 14. Free-Running Frequency

Missing-Pulse Detector

The circuit shown in Figure 15 can be used to detect a missing pulse or abnormally long spacing between consecutive pulses in a train of pulses. The timing interval of the monostable circuit is retriggered continuously by the input pulse train as long as the pulse spacing is less than the timing interval. A longer pulse spacing, missing pulse, or terminated pulse train permits the timing interval to be completed, thereby generating an output pulse as shown in Figure 16.



Pin numbers shown are shown for the D, JG, P, PS, and PW packages.

 $V_{CC} = 5 V$ $R_A = 1 k\Omega$ $C = 0.1 \mu F$ See Figure 15 Voltage – 2 V/div Input Voltage **Output Voltage** Capacitor Voltage

Figure 16. Completed Timing Waveforms for Missing-Pulse Detector

Time - 0.1 ms/div

Figure 15. Circuit for Missing-Pulse Detector



Frequency Divider

By adjusting the length of the timing cycle, the basic circuit of Figure 9 can be made to operate as a frequency divider. Figure 17 shows a divide-by-three circuit that makes use of the fact that retriggering cannot occur during the timing cycle.

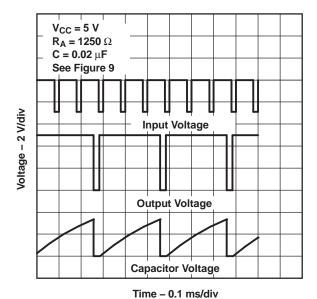
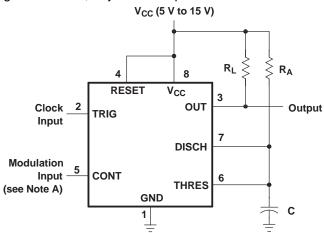


Figure 17. Divide-by-Three Circuit Waveforms



Pulse-Width Modulation

The operation of the timer can be modified by modulating the internal threshold and trigger voltages, which is accomplished by applying an external voltage (or current) to CONT. Figure 18 shows a circuit for pulse-width modulation. A continuous input pulse train triggers the monostable circuit, and a control signal modulates the threshold voltage. Figure 19 shows the resulting output pulse-width modulation. While a sine-wave modulation signal is shown, any wave shape could be used.



Pin numbers shown are for the D, JG, P, PS, and PW packages.

NOTE A: The modulating signal can be direct or capacitively coupled to CONT. For direct coupling, the effects of modulation source voltage and impedance on the bias of the timer should be considered.

Figure 18. Circuit for Pulse-Width Modulation

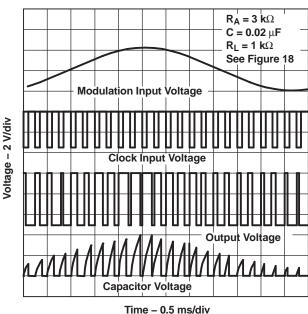
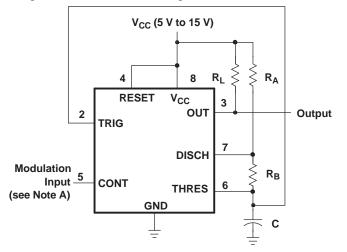


Figure 19. Pulse-Width-Modulation Waveforms



Pulse-Position Modulation

As shown in Figure 20, any of these timers can be used as a pulse-position modulator. This application modulates the threshold voltage and, thereby, the time delay, of a free-running oscillator. Figure 21 shows a triangular-wave modulation signal for such a circuit; however, any wave shape could be used.



Pin numbers shown are for the D, JG, P, PS, and PW packages.

NOTE A: The modulating signal can be direct or capacitively coupled to CONT. For direct coupling, the effects of modulation source voltage and impedance on the bias of the timer should be considered.

 $R_{A} = 3 \text{ k}\Omega$ $R_{B} = 500 \Omega$ $R_{L} = 1 \text{ k}\Omega$ See Figure 20

Output Voltage

Capacitor Voltage

Time - 0.1 ms/div

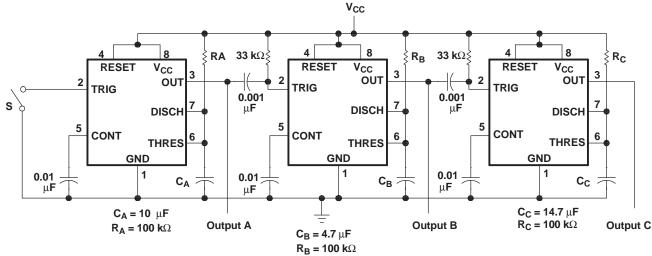
Figure 20. Circuit for Pulse-Position Modulation

Figure 21. Pulse-Position-Modulation Waveforms



Sequential Timer

Many applications, such as computers, require signals for initializing conditions during start-up. Other applications, such as test equipment, require activation of test signals in sequence. These timing circuits can be connected to provide such sequential control. The timers can be used in various combinations of astable or monostable circuit connections, with or without modulation, for extremely flexible waveform control. Figure 22 shows a sequencer circuit with possible applications in many systems, and Figure 23 shows the output waveforms.



Pin numbers shown are for the D, JG, P, PS, and PW packages.

NOTE A: S closes momentarily at t = 0.

Figure 22. Sequential Timer Circuit

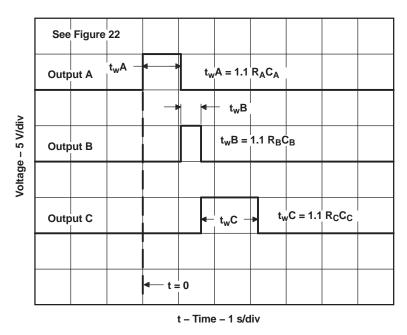


Figure 23. Sequential Timer Waveforms

23-May-2012

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
JM38510/10901BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	
M38510/10901BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	
NA555D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NA555DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NA555DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NA555DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NA555P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NA555PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE555D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555DRG3	PREVIEW	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
NE555DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE555PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
NE555PSLE	OBSOLETE	SO	PS	8		TBD	Call TI	Call TI	
NE555PSR	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PSRE4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



23-May-2012

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
NE555PSRG4	ACTIVE	SO	PS	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PWE4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PWRE4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555PWRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
NE555Y	OBSOLETE			0		TBD	Call TI	Call TI	
SA555D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555DE4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555DRE4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SA555P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SA555PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	
SE555D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SE555DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SE555DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	



www.ti.com 23-May-2012

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
SE555DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	
SE555FKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	
SE555JG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	
SE555JGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	
SE555N	OBSOLETE	PDIP	N	8		TBD	Call TI	Call TI	
SE555P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF SE555, SE555M:

Catalog: SE555



www.ti.com 23-May-2012

Military: SE555M

• Space: SE555-SP, SE555-SP

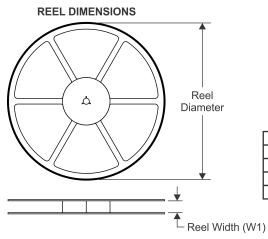
NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

www.ti.com 28-Nov-2012

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
NA555DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NA555DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE555DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE555DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE555DRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
NE555PSR	SO	PS	8	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
NE555PWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
SA555DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
SE555DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 28-Nov-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
NA555DR	SOIC	D	8	2500	340.5	338.1	20.6
NA555DR	SOIC	D	8	2500	367.0	367.0	35.0
NE555DR	SOIC	D	8	2500	340.5	338.1	20.6
NE555DRG4	SOIC	D	8	2500	340.5	338.1	20.6
NE555DRG4	SOIC	D	8	2500	367.0	367.0	35.0
NE555PSR	SO	PS	8	2000	367.0	367.0	38.0
NE555PWR	TSSOP	PW	8	2000	367.0	367.0	35.0
SA555DR	SOIC	D	8	2500	340.5	338.1	20.6
SE555DR	SOIC	D	8	2500	367.0	367.0	35.0

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PS (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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